Attorney's Docket No.: 14952.0274 (

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

icant: Moungi BAWENDI et al.

Art Unit : 1639

Appln. No.: 10/632,922

Examiner:

Filed

: August 4, 2003

Title

: SEMICONDUCTOR NANOCRYSTALS FOR INVENTORY CONTROL

United States Patent and Trademark Office Customer Service Window Randolph Building 401 Dulany Street Alexandria, VA 22314

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

As a means of complying with the duty of disclosure under 37 CFR §1.56, and in accordance with 37 CFR §§1.97 and 1.98, Applicants, through the undersigned attorney, submit this Supplemental Information Disclosure Statement along with the references listed on the attached form PTO-1449.

Attached is a \$180.00 filing fee check. Please apply any additional charges or credits to Deposit Account No. 19-4293.

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Respectfully submitted,

Date: 10-19-05

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Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 14952.0274 CIP DIV	Application No. 10/632,922		
Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b))		Applicant Moungi BAWENDI, et al.		OIP	ie,
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	Other De	suments (include Author Title Date and Place of Publication)
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Examiner Signature	Date Considered			
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with				
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AP	Ekimov, A.I. et al., "Enhancement of Exciton Exchange Interaction by Quantum Confinement in CdSe Nanocrystals," <i>Jpn. J. Appl. Phys</i> , Vol. 34, 12-14 (1994).		
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AW	Ekimov, A.I. et al. "Generation of reflected second harmonic at semiconductor quantum dots," <i>JETP Letters</i> , Vol. 55, No. 8, 435-439 (1992).		
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	Substitute Disclosure Form (PTO-1449)		

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	BJ	Ekimov, A.I. et al., "Photoluminescence of quasizero-dimensional semiconductor structures," Sov. Phys. Solid State 31(8), August 1989, pp. 1385-93.		
	BK	Ekimov, A.I. et al., "Photoionization of semiconducting microcrystals in glass," Sov. Phys. Solid State 31(1), January 1989, pp. 149-151.		
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	BN	Ekimov, A.I. et al., "Nonlinear optical properties of semiconductor microcrystals," <i>JETP Lett.</i> , Vol. 46, No. 10, 25 November 1987 pp. 435-439.		
	ВО	Ekimov, A.I. et al., "Quantization of the energy spectrum of holes in the adiabatic potential of the electron," <i>JETP Lett.</i> , Vol. 43, No. 6, 25 March 1986, pp. 376-379.		
-	BP	Ekimov, A.I. et al., "Quantum Size Effect in Semiconductor Microcrystals," Solid State Communications, Vol. 56, No. 11, pp. 921-924, 1985.		
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